



# MONOLITHIC PHOTODIODE AND SINGLE-SUPPLY TRANSIMPEDANCE AMPLIFIER

## FEATURES

- **SINGLE SUPPLY:** +2.7 to +36V
- **PHOTODIODE SIZE:** 0.090 x 0.090 inch
- **INTERNAL 1MΩ FEEDBACK RESISTOR**
- **HIGH RESPONSIVITY:** 0.45A/W (650nm)
- **BANDWIDTH:** 14kHz at  $R_F = 1M\Omega$
- **LOW QUIESCENT CURRENT:** 120μA
- **AVAILABLE IN 8-PIN DIP AND 8-LEAD SURFACE-MOUNT PACKAGES**

## APPLICATIONS

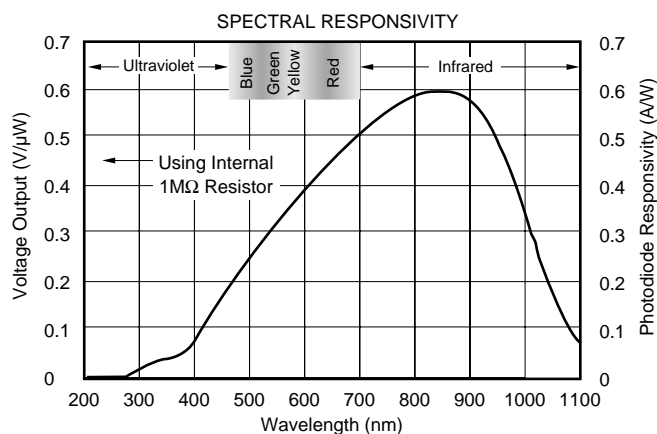
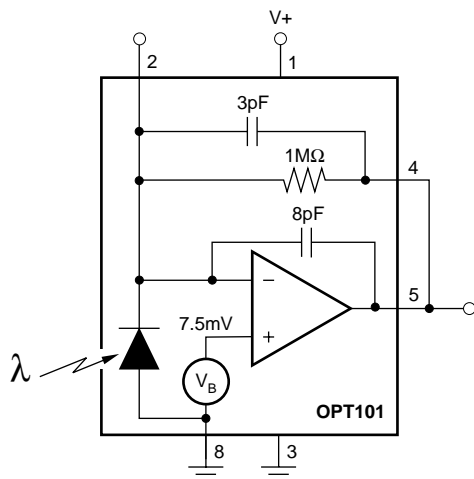
- **MEDICAL INSTRUMENTATION**
- **LABORATORY INSTRUMENTATION**
- **POSITION AND PROXIMITY SENSORS**
- **PHOTOGRAPHIC ANALYZERS**
- **BARCODE SCANNERS**
- **SMOKE DETECTORS**
- **CURRENCY CHANGERS**

## DESCRIPTION

The OPT101 is a monolithic photodiode with on-chip transimpedance amplifier. Output voltage increases linearly with light intensity. The amplifier is designed for single or dual power-supply operation, making it ideal for battery-operated equipment.

The integrated combination of photodiode and transimpedance amplifier on a single chip eliminates the problems commonly encountered in discrete designs such as leakage current errors, noise pick-up, and gain peaking due to stray capacitance. The 0.09 x 0.09 inch photodiode is operated in the photoconductive mode for excellent linearity and low dark current.

The OPT101 operates from +2.7V to +36V supplies and quiescent current is only 120μA. It is available in clear plastic 8-pin DIP, and J-formed DIP for surface mounting. Temperature range is 0°C to +70°C.



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PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.

# SPECIFICATIONS

At  $T_A = +25^\circ\text{C}$ ,  $V_S = +2.7\text{V}$  to  $+36\text{V}$ ,  $\lambda = 650\text{nm}$ , internal  $1\text{M}\Omega$  feedback resistor, and  $R_L = 10\text{k}\Omega$ , unless otherwise noted.

PARAMETER	CONDITIONS	OPT101P			UNITS
		MIN	TYP	MAX	
<b>RESPONSIVITY</b> Photodiode Current Voltage Output vs Temperature Unit to Unit Variation Nonlinearity <sup>(1)</sup> Photodiode Area	650nm 650nm 650nm FS Output = 24V (0.090 x 0.090in) (2.29 x 2.29mm)		0.45 0.45 100 $\pm 5$ $\pm 0.01$ 0.008 5.2		A/W V/ $\mu\text{W}$ ppm/ $^\circ\text{C}$ % % of FS in <sup>2</sup> mm <sup>2</sup>
<b>DARK ERRORS, RTO<sup>(2)</sup></b> Offset Voltage, Output vs Temperature vs Power Supply Voltage Noise, Dark, $f_B = 0.1\text{Hz}$ to $20\text{kHz}$	$V_S = +2.7\text{V}$ to $+36\text{V}$ $V_S = +15\text{V}$ , $V_{\text{PIN}3} = -15\text{V}$	+5	+7.5 $\pm 10$ 10 300	+10 100	mV $\mu\text{V}/^\circ\text{C}$ $\mu\text{V}/\text{V}$ $\mu\text{Vrms}$
<b>TRANSIMPEDANCE GAIN</b> Resistor Tolerance, P W vs Temperature			1 $\pm 0.5$ $\pm 0.5$ $\pm 50$	$\pm 2$	$\text{M}\Omega$ % % ppm/ $^\circ\text{C}$
<b>FREQUENCY RESPONSE</b> Bandwidth Rise Fall Time, 10% to 90% Settling Time, 0.05% 0.1% 1% Overload Recovery	$V_{\text{OUT}} = 10\text{Vp-p}$ $V_{\text{OUT}} = 10\text{V Step}$ $V_{\text{OUT}} = 10\text{V Step}$ 100%, Return to Linear Operation		14 28 160 80 70 50		kHz $\mu\text{s}$ $\mu\text{s}$ $\mu\text{s}$ $\mu\text{s}$ $\mu\text{s}$
<b>OUTPUT</b> Voltage Output, High Capacitive Load, Stable Operation Short-Circuit Current	$V_S = 36\text{V}$	$(V_S) - 1.3$	$(V_S) - 1.15$ 10 15		V nF mA
<b>POWER SUPPLY</b> Operating Voltage Range Quiescent Current	Dark, $V_{\text{PIN}3} = 0\text{V}$ $R_L = \infty$ , $V_{\text{OUT}} = 10\text{V}$	+2.7	120 220	+36 240	V $\mu\text{A}$ $\mu\text{A}$
<b>TEMPERATURE RANGE</b> Specification Operating Storage Thermal Resistance, $\theta_{\text{JA}}$		0 0 -25		+70 +70 +85	$^\circ\text{C}$ $^\circ\text{C}$ $^\circ\text{C}$ $^\circ\text{C}/\text{W}$

NOTES: (1) Deviation in percent of full scale from best-fit straight line. (2) Referred to Output. Includes all error sources.

# PHOTODIODE SPECIFICATIONS

$T_A = +25^\circ\text{C}$ ,  $V_S = +2.7\text{V}$  to  $+36\text{V}$  unless otherwise noted.

PARAMETER	CONDITIONS	Photodiode of OPT101P			UNITS
		MIN	TYP	MAX	
Photodiode Area	(0.090 x 0.090in) (2.29 x 2.29mm)		0.008 5.2		in <sup>2</sup> mm <sup>2</sup>
Current Responsivity	650nm 650nm		0.45 865		A/W $\mu\text{A}/\text{W}/\text{cm}^2$
Dark Current vs Temperature	$V_{\text{DIODE}} = 7.5\text{mV}$		2.5 Doubles every $7^\circ\text{C}$		pA
Capacitance			1200		pF

# OP AMP SPECIFICATIONS

At  $T_A = +25^\circ\text{C}$ ,  $V_S = +2.7\text{V}$  to  $+36\text{V}$ ,  $\lambda = 650\text{nm}$ , internal  $1\text{M}\Omega$  feedback resistor, and  $R_L = 10\text{k}\Omega$ , unless otherwise noted.

PARAMETER	CONDITIONS	OPT101 Op Amp <sup>(1)</sup>			UNITS
		MIN	TYP	MAX	
<b>INPUT</b> Offset Voltage vs Temperature vs Power Supply Input Bias Current vs Temperature Input Impedance Differential Common-Mode Common-Mode Input Voltage Range Common-Mode Rejection	(-) Input (-) Input  Linear Operation		$\pm 0.5$ $\pm 2.5$ 10 165 Doubles every $10^\circ\text{C}$  400    5 250    35 0 to $[(V_S) - 1]$ 90		mV $\mu\text{V}/^\circ\text{C}$ $\mu\text{V}/\text{V}$ pA  $\text{M}\Omega$    pF $\text{G}\Omega$    pF V dB
<b>OPEN-LOOP GAIN</b> Open-loop Voltage Gain			90		dB
<b>FREQUENCY RESPONSE</b> Gain-Bandwidth Product <sup>(2)</sup> Slew Rate Settling Time 1% 0.1% 0.05%			2 1 5.8 7.7 8.0		MHz V/ $\mu\text{s}$ $\mu\text{s}$ $\mu\text{s}$ $\mu\text{s}$
<b>OUTPUT</b> Voltage Output, High Short-Circuit Current	$V_S = +36\text{V}$	$(V_S) - 1.3$	$(V_S) - 1.15$ 15		V mA
<b>POWER SUPPLY</b> Operating Voltage Range Quiescent Current	Dark, $V_{\text{PIN3}} = 0\text{V}$ $R_L = \infty$ , $V_{\text{OUT}} = 10\text{V}$	+2.7	120 220	+36 240	V $\mu\text{A}$ $\mu\text{A}$

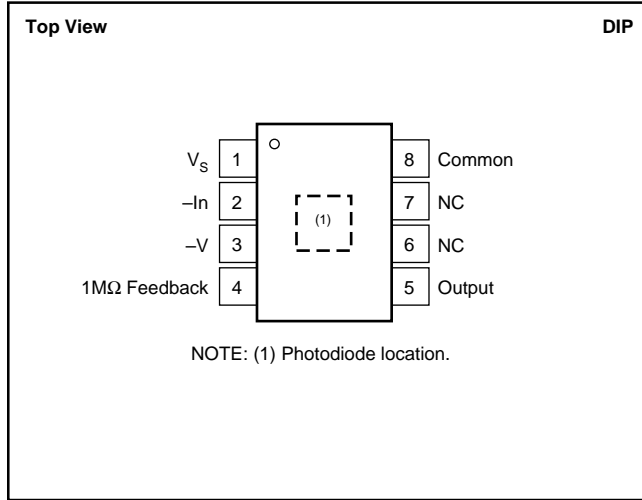
NOTES: (1) Op amp specifications provided for information and comparison only. (2) Stable gains  $\geq 10\text{V}/\text{V}$ .

## PACKAGE/ORDERING INFORMATION<sup>(1)</sup>

PRODUCT	PACKAGE-LEAD	PACKAGE DESIGNATOR	SPECIFIED TEMPERATURE RANGE	PACKAGE MARKING	ORDERING NUMBER	TRANSPORT MEDIA, QUANTITY
OPT101P	DIP-8	NTC	-25°C to +85°C	OPT101	OPT101P	Rail, 50
OPT101P-J	DIP-8, Surface Mount <sup>(2)</sup>	DTL	-25°C to +85°C	OPT101	OPT101P-J	Rail, 50

NOTES: (1) For the most current package and ordering information, see the Package Option Addendum at the end of this data sheet. (2) 8-pin DIP with J-formed leads for surface mounting.

## PIN CONFIGURATIONS



## ABSOLUTE MAXIMUM RATINGS<sup>(1)</sup>

Supply Voltage ( $V_S$ to "Common" or pin 3) .....	0 to +36V
Output Short-Circuit (to ground) .....	Continuous
Operating Temperature .....	-25°C to +85°C
Storage Temperature .....	-25°C to +85°C
Junction Temperature .....	+85°C
Lead Temperature (soldering, 10s) .....	+300°C (Vapor-Phase Soldering Not Recommended)

NOTE: (1) Stresses above these ratings may cause permanent damage. Exposure to absolute maximum conditions for extended periods may degrade device reliability. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those specified is not implied.



## ELECTROSTATIC DISCHARGE SENSITIVITY

This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.



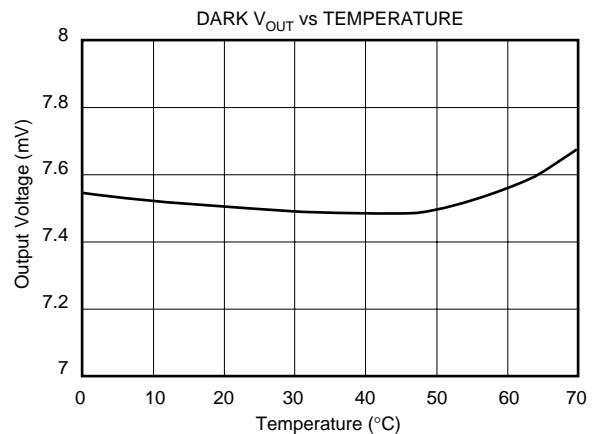
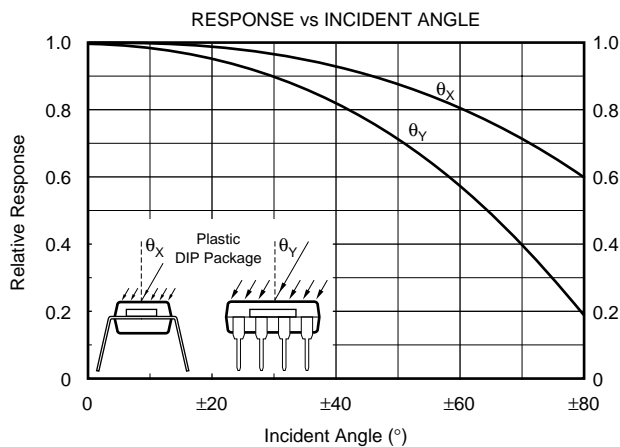
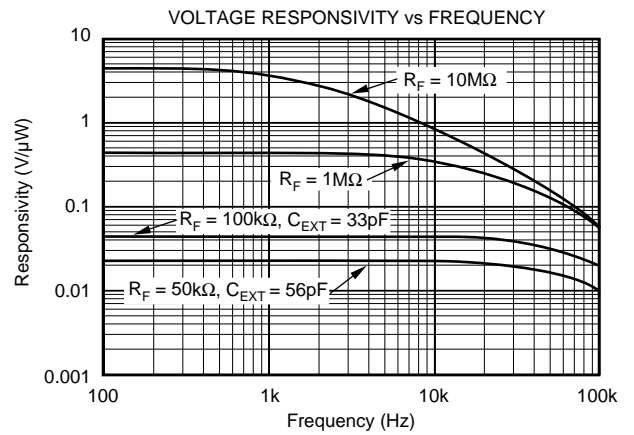
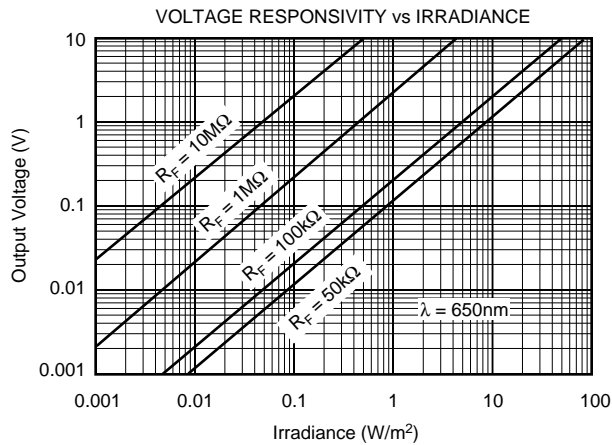
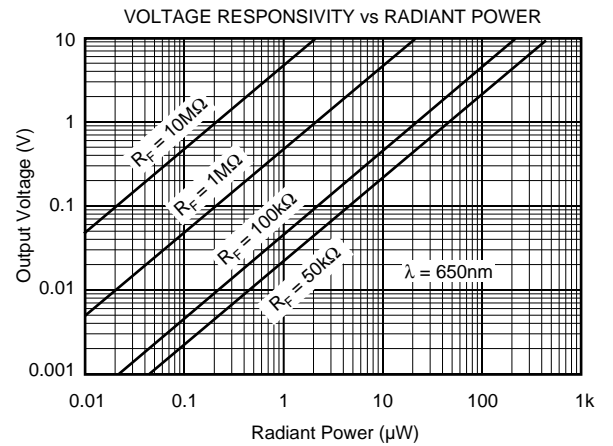
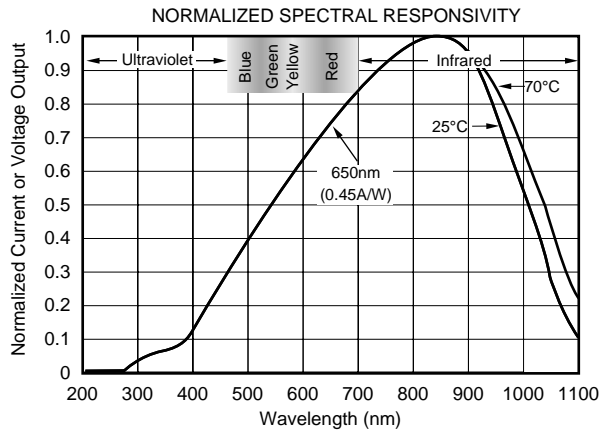
## MOISTURE SENSITIVITY AND SOLDERING

Clear plastic does not contain the structural-enhancing fillers used in black plastic molding compound. As a result, clear plastic is more sensitive to environmental stress than black plastic. This can cause difficulties if devices have been stored in high humidity prior to soldering. The rapid heating during soldering can stress wire bonds and cause failures. Prior to soldering, it is recommended that plastic devices be baked-out at +85°C for 24 hours.

The fire-retardant fillers used in black plastic are not compatible with clear molding compound. The OPT101 plastic packages cannot meet flammability test, UL-94.

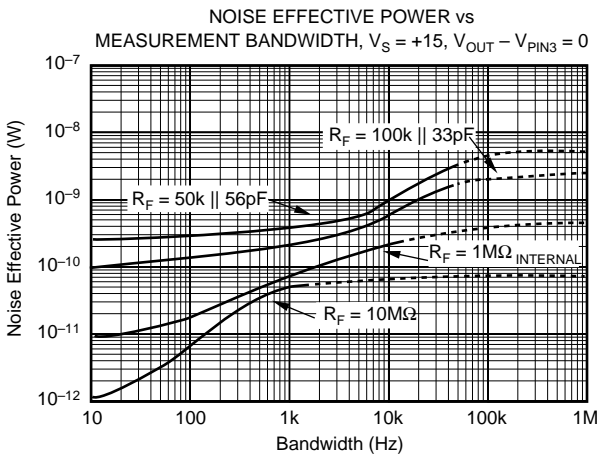
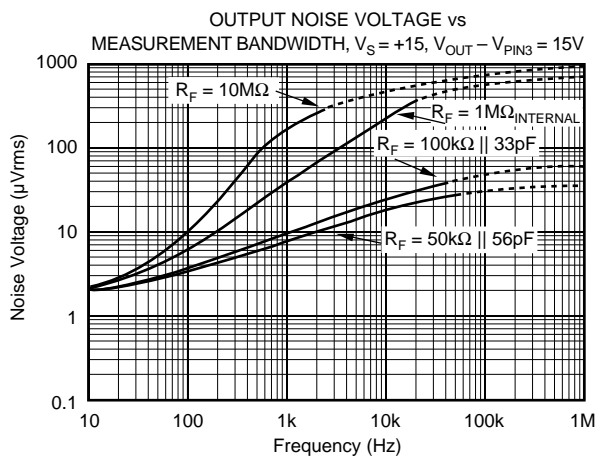
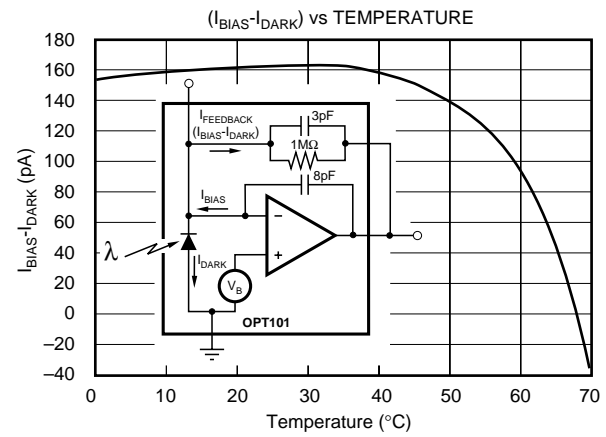
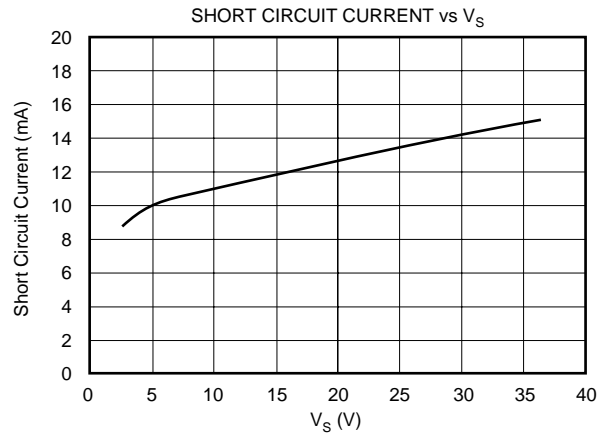
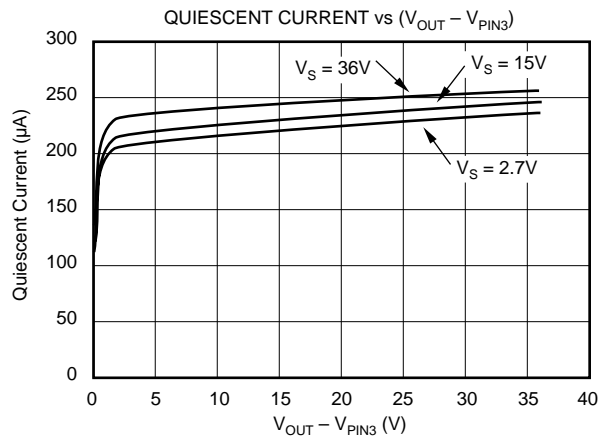
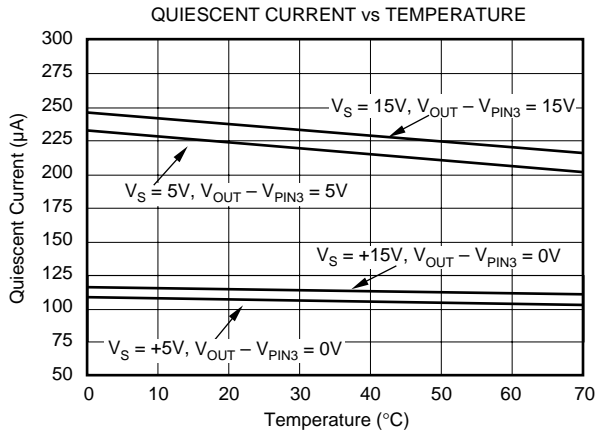
# TYPICAL PERFORMANCE CURVES

At  $T_A = +25^\circ\text{C}$ ,  $V_S = +2.7\text{V}$  to  $+36\text{V}$ ,  $\lambda = 650\text{nm}$ , internal  $1\text{M}\Omega$  feedback resistor, and  $R_L = 10\text{k}\Omega$ , unless otherwise noted.



# TYPICAL PERFORMANCE CURVES (Cont.)

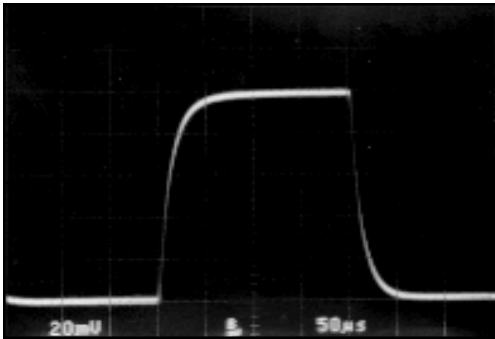
At  $T_A = +25^\circ\text{C}$ ,  $V_S = +2.7\text{V}$  to  $+36\text{V}$ ,  $\lambda = 650\text{nm}$ , internal  $1\text{M}\Omega$  feedback resistor, and  $R_L = 10\text{k}\Omega$ , unless otherwise noted.



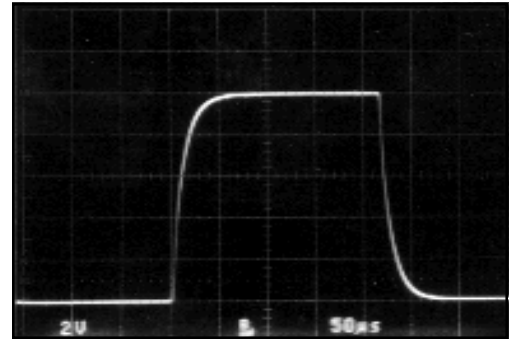
# TYPICAL PERFORMANCE CURVES (Cont.)

At  $T_A = +25^\circ\text{C}$ ,  $V_S = +2.7\text{V}$  to  $+36\text{V}$ ,  $\lambda = 650\text{nm}$ , internal  $1\text{M}\Omega$  feedback resistor, and  $R_L = 10\text{k}\Omega$ , unless otherwise noted.

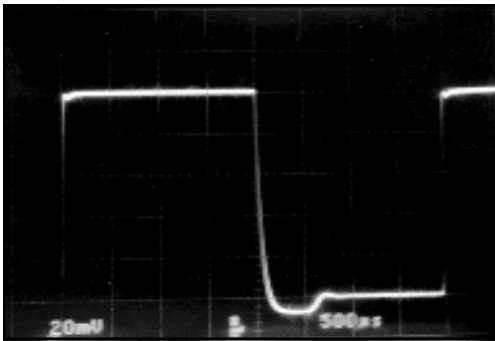
SMALL SIGNAL RESPONSE



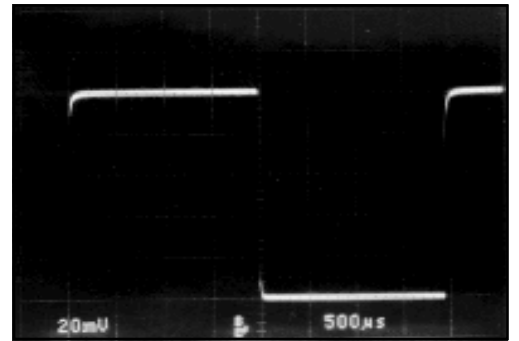
LARGE SIGNAL RESPONSE



SMALL SIGNAL RESPONSE ( $C_{\text{LOAD}} = 10,000\text{ pF}$ )  
(Pin 3 = 0V)



SMALL SIGNAL RESPONSE ( $C_{\text{LOAD}} = 10,000\text{ pF}$ )  
(Pin 3 = -15V)



# APPLICATIONS INFORMATION

Figure 1 shows the basic connections required to operate the OPT101. Applications with high-impedance power supplies may require decoupling capacitors located close to the device pins as shown. Output is 7.5mV dc with no light and increases with increasing illumination.

Photodiode current,  $I_D$ , is proportional to the radiant power, or flux, (in watts) falling on the photodiode. At a wavelength of 650nm (visible red) the photodiode Responsivity,  $R_F$ , is approximately 0.45A/W. Responsivity at other wavelengths is shown in the typical performance curve "Responsivity vs Wavelength."

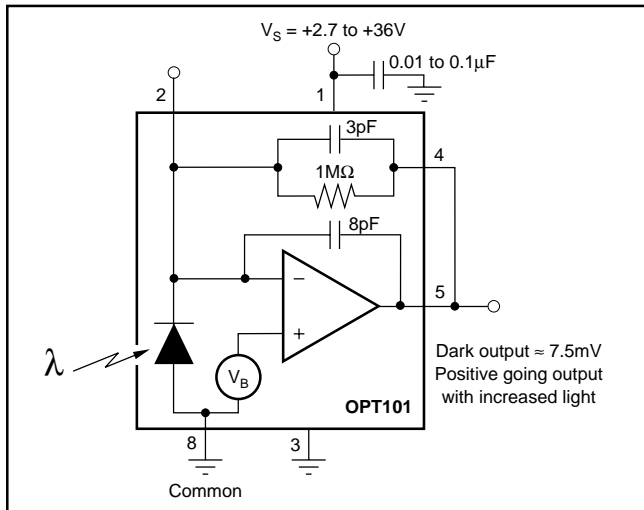


FIGURE 1. Basic Circuit Connections.

The typical performance curve "Output Voltage vs Radiant Power" shows the response throughout a wide range of radiant power. The response curve "Output Voltage vs Irradiance" is based on the photodiode area of 5.2mm<sup>2</sup>.

The OPT101's voltage output is the product of the photodiode current times the feedback resistor, ( $I_D R_F$ ), plus a pedestal voltage,  $V_B$ , of approximately 7.5mV introduced for single supply operation. The internal feedback resistor is laser trimmed to 1MΩ. Using this resistor, the output voltage responsivity,  $R_V$ , is approximately 0.45V/μW at 650nm wavelength. Figure 1 shows the basic circuit connections for the OPT101 operating with a single power supply and using the internal 1MΩ feedback resistor for a response of 0.45V/μW at 650nm. Pin 3 is connected to common in this configuration.

## CAPACITIVE LOADING

The OPT101 is capable of driving load capacitances of 10nF without instability. However, dynamic performance with capacitive loads can be improved by applying a negative bias voltage to Pin 3 (shown in Figure 2). This negative power supply voltage allows the output to go negative in response to the reactive effect of a capacitive load. An internal JFET connected between pin 5 (output) and pin 3 allows the output to sink current. This current sink capability can also be useful when driving the capacitive inputs of some analog-to-digital converters which require the signal

source to sink currents up to approximately 100μA. The benefits of this current sink are shown in the typical performance curves "Small Signal Response ( $C_{LOAD} = 10,000pF$ )" which compare operation with pin 3 grounded and connected to -15V.

Due to the architecture of this output stage current sink, there is a slight increase in operating current when there is a voltage between pin 3 and the output. Depending on the magnitude of this voltage, the quiescent current will increase by approximately 100μA as shown in the typical performance curve "Quiescent Current vs ( $V_{OUT} - V_{PIN3}$ )".

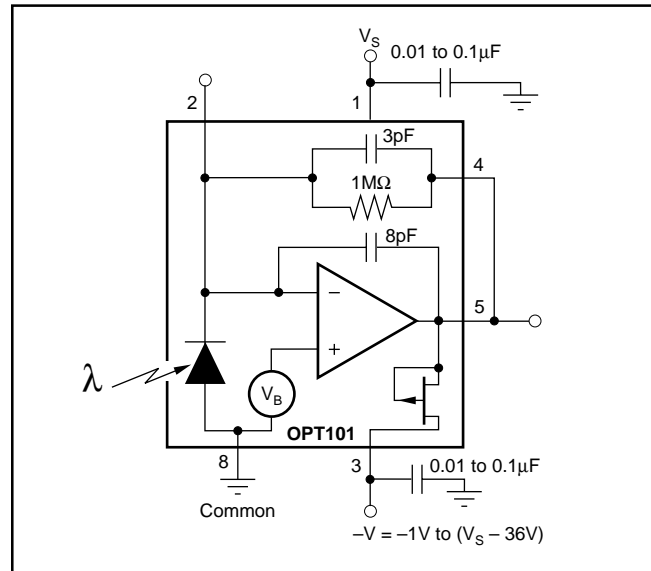


FIGURE 2. Bipolar Power Supply Circuit Connections.

## NOISE PERFORMANCE

Noise performance of the OPT101 is determined by the op amp characteristics, feedback components and photodiode capacitance. The typical performance curve "Output Noise Voltage vs Measurement Bandwidth" shows how the noise varies with  $R_F$  and measured bandwidth (0.1Hz to the indicated frequency), when the output voltage minus the voltage on pin 3 is greater than approximately 50mV. Below this level, the output stage is powered down, and the effective bandwidth is decreased. This reduces the noise to approximately 1/3 the nominal noise value of 300μVrms, or 100μVrms. This enables a low level signal to be resolved.

Noise can be reduced by filtering the output with a cutoff frequency equal to the signal bandwidth. This will improve signal-to-noise ratio. Also, output noise increases in proportion to the square root of the feedback resistance, while responsivity increases linearly with feedback resistance. Best signal-to-noise ratio is achieved with large feedback resistance. This comes with the trade-off of decreased bandwidth.

The noise performance of the photodetector is sometimes characterized by *Noise Effective Power* (NEP). This is the radiant power that would produce an output signal equal to the noise level. NEP has the units of radiant power (watts), or Watts/√Hz to convey spectral information about the noise. The typical performance curve "Noise Effective Power" vs Measurement Bandwidth" illustrates the NEP for the OPT101.



## DARK ERRORS

The dark errors in the specification table include all sources. The dominant source of dark output voltage is the “pedestal” voltage applied to the non-inverting input of the op amp. This voltage is introduced to provide linear operation in the absence of light falling on the photodiode. Photodiode dark current is approximately 2.5pA and contributes virtually no offset error at room temperature. The bias current of the op amp's summing junction (– input) is approximately 165pA. The dark current will be subtracted from the amplifier's bias current, and this residual current will flow through the feedback resistor creating an offset. The effects of temperature on this difference current can be seen in the typical performance curve “(I<sub>BIAS</sub> – I<sub>DARK</sub>) vs Temperature.” The dark output voltage can be trimmed to zero with the optional circuit shown in Figure 3. A low impedance offset driver (op amp) should be used to drive pin 8 because this node has signal-dependent currents.

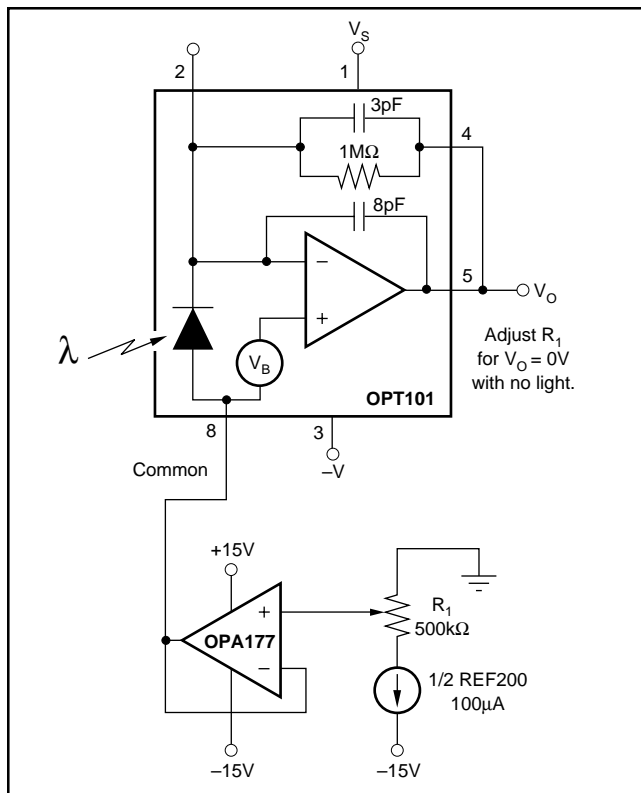


FIGURE 3. Dark Error (Offset) Adjustment Circuit.

## CHANGING RESPONSIVITY

An external resistor, R<sub>EXT</sub>, can be connected to set a different voltage responsivity. To increase the responsivity, this resistor can be placed in series with the internal 1MΩ (Figure 4a), or the external resistor can replace the internal resistor by not connecting pin 4 (Figure 4b). The second configuration also allows the circuit gain to be reduced below 10<sup>6</sup>V/A by using external resistors of less than 1MΩ.

Figure 4 includes tables showing the responsivity and bandwidth. For values of R<sub>F</sub> less than 1MΩ, an external capacitor, C<sub>EXT</sub>, should be connected in parallel with R<sub>F</sub>.

This capacitor eliminates gain peaking and prevents instability. The value of C<sub>EXT</sub> can be determined from the table in Figure 4. Values of R<sub>F</sub>, other than shown in the table, can be interpolated.

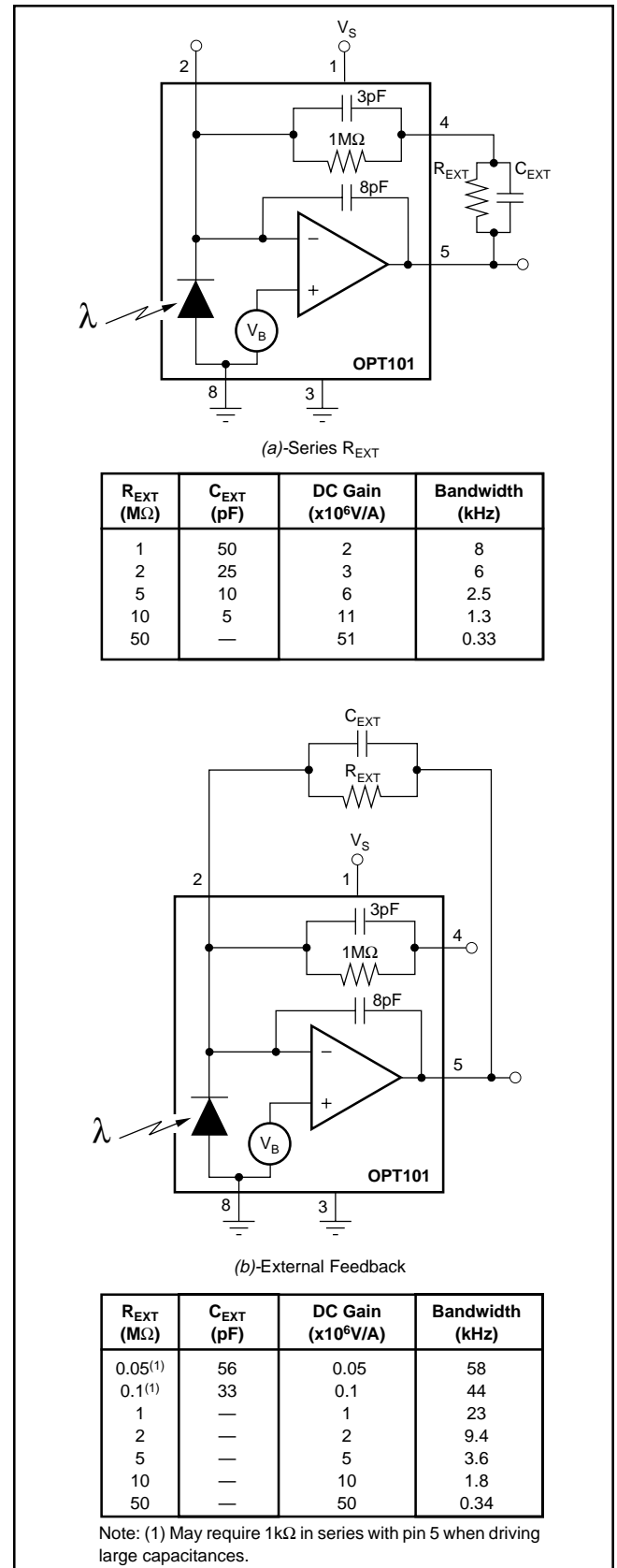


FIGURE 4. Changing Responsivity with External Resistor.

Applications using a feedback resistor significantly larger than the internal  $1\text{M}\Omega$  resistor may require special consideration. Input bias current of the op amp and dark current of the photodiode increase significantly at higher temperatures. This increase combined with the higher gain ( $R_F > 1\text{M}\Omega$ ) can cause the op amp output to be driven to ground at high temperatures. Such applications may require a positive bias voltage applied to pin 8 to ensure that the op amp output remains in the linear operating region when the photodiode is not exposed to light. Alternatively, a dual power supply can be used. The output may be negative when sensing dark conditions.

## LIGHT SOURCE POSITIONING

The OPT101 is tested with a light source that uniformly illuminates the full area of the integrated circuit, including the op amp. Although IC amplifiers are light-sensitive to some degree, the OPT101 op amp circuitry is designed to minimize this effect. Sensitive junctions are shielded with metal, and the photodiode area is very large relative to the op amp input circuitry.

If your light source is focused to a small area, be sure that it is properly aimed to fall on the photodiode. A narrowly focused beam falling on only the photodiode will provide improved settling times compared to a source that uniformly illuminates the full area of the die. If a narrowly focused light source were to miss the photodiode area and fall only on the op amp circuitry, the OPT101 would not perform properly. The large  $0.09" \times 0.09"$  ( $2.29\text{mm} \times 2.29\text{mm}$ ) photodiode area allows easy positioning of narrowly focused light sources. The photodiode area is easily visible, as it appears very dark compared to the surrounding active circuitry.

The incident angle of the light source also effects the apparent sensitivity in uniform irradiance. For small incident angles, the loss in sensitivity is simply due to the smaller effective light gathering area of the photodiode (proportional to the cosine of the angle). At a greater incident angle, light is diffracted and scattered by the package. These effects are shown in the typical performance curve "Responsivity vs Incident Angle."

## DYNAMIC RESPONSE

Using the internal  $1\text{M}\Omega$  resistor, the dynamic response of the photodiode/op amp combination can be modeled as a simple  $R \cdot C$  circuit with a  $-3\text{dB}$  cutoff frequency of approximately  $14\text{kHz}$ . The  $R$  and  $C$  values are  $1\text{M}\Omega$  and  $11\text{pF}$  respectively. By using external resistors, with less than  $3\text{pF}$  parasitic capacitance, the frequency response can be improved. An external  $1\text{M}\Omega$  resistor used in the configuration shown in Figure 4b will create a  $23\text{kHz}$  bandwidth with the same  $10^6\text{V/A}$  dc transimpedance gain. This yields a rise time of approximately  $15\mu\text{s}$  (10% to 90%). Dynamic response is not limited by op amp slew rate. This is demonstrated by the dynamic response oscilloscope photographs showing virtually identical large-signal and small-signal response.

Dynamic response will vary with feedback resistor value as shown in the typical performance curve "Responsivity vs Frequency." Rise time (10% to 90%) will vary according to the  $-3\text{dB}$  bandwidth produced by a given feedback resistor value:

$$t_r = \frac{0.35}{f_C}$$

where:

$t_r$  is the rise time (10% to 90%)

$f_C$  is the  $-3\text{dB}$  bandwidth

## LINEARITY PERFORMANCE

The photodiode is operated in the photoconductive mode so the current output of the photodiode is very linear with radiant power throughout a wide range. Nonlinearity remains below approximately 0.05% up to  $100\mu\text{A}$  photodiode current. The photodiode can produce output currents of  $1\text{mA}$  or greater with high radiant power, but nonlinearity increases to several percent in this region.

This very linear performance at high radiant power assumes that the full photodiode area is uniformly illuminated. If the light source is focused to a small area of the photodiode, nonlinearity will occur at lower radiant power.

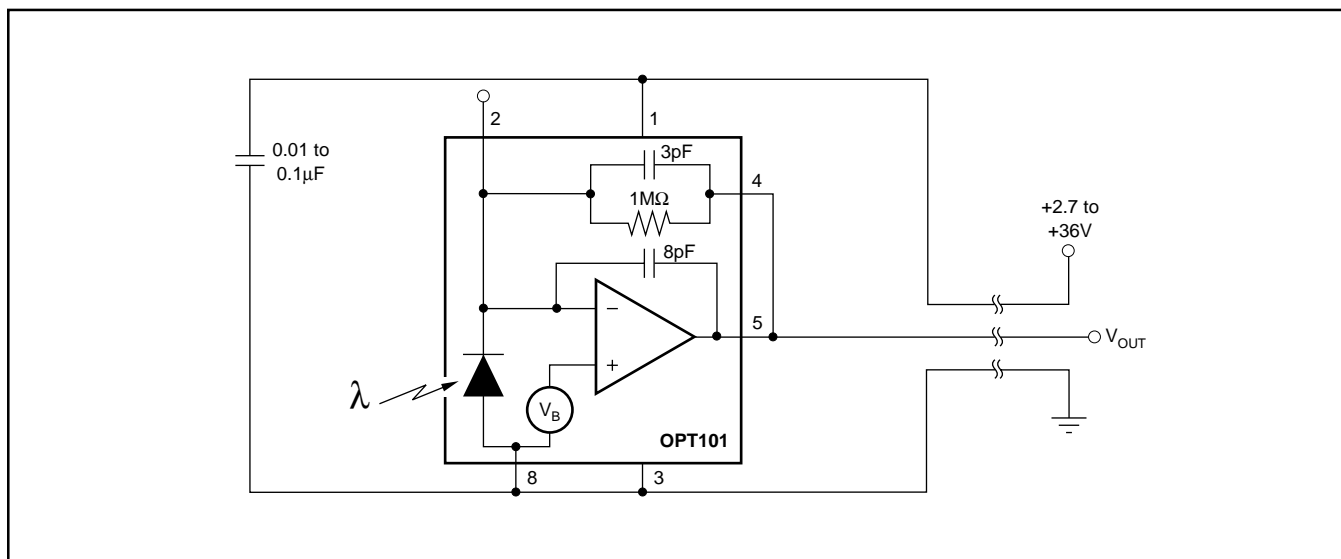


FIGURE 5. Three-Wire Remote Light Measurement.

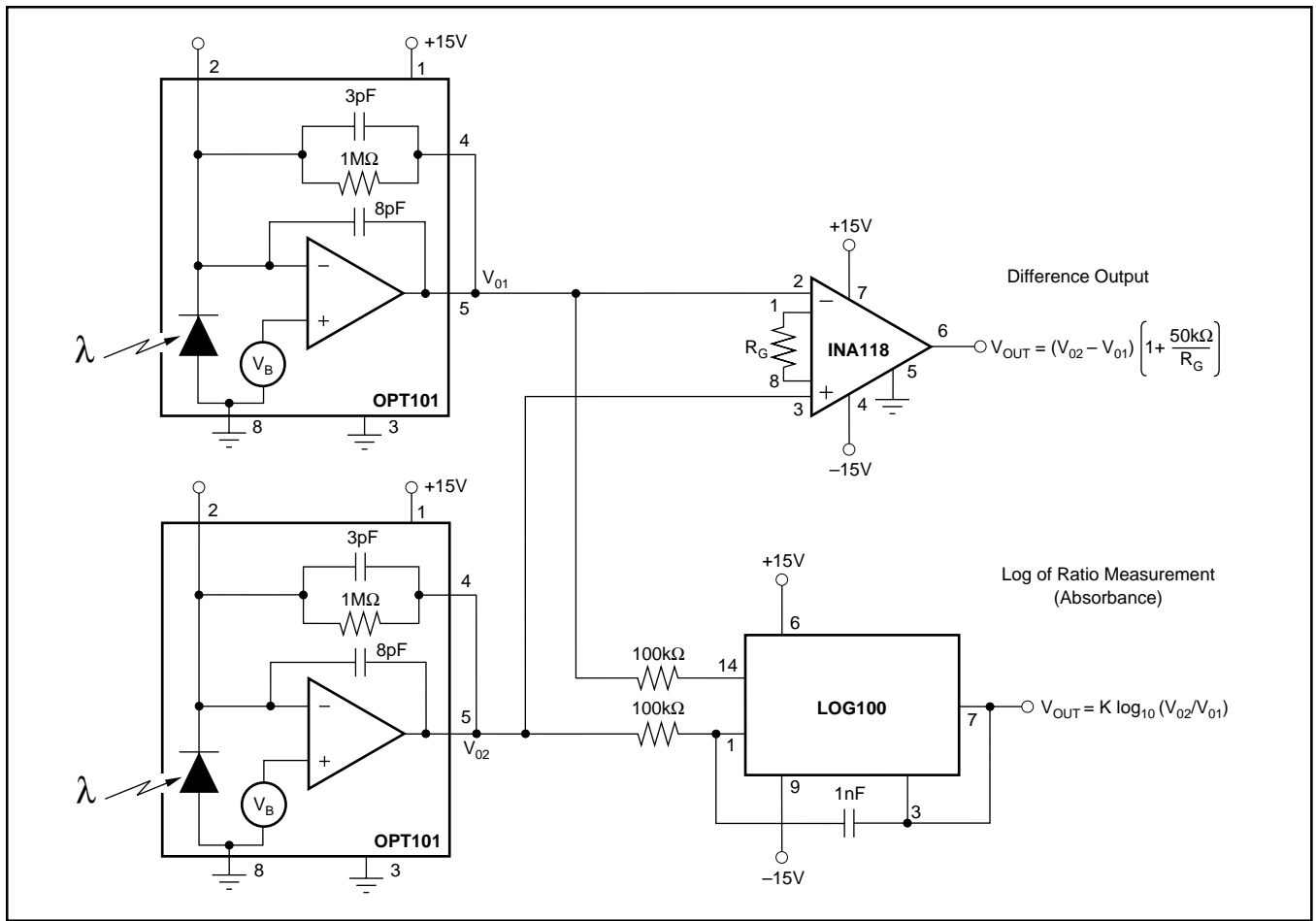


FIGURE 6. Differential Light Measurement.

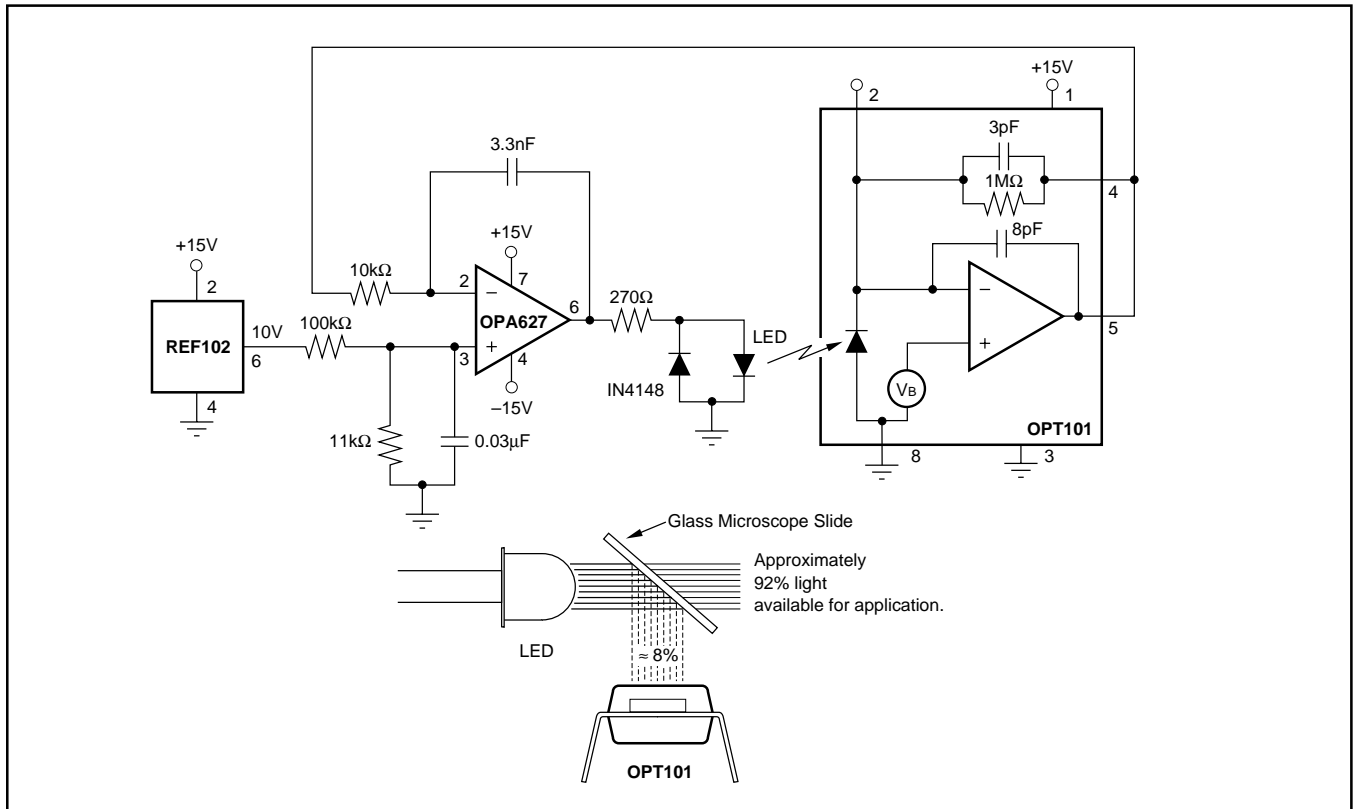


FIGURE 7. LED Output Regulation Circuit.

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## PACKAGING INFORMATION

ORDERABLE DEVICE	STATUS(1)	PACKAGE TYPE	PACKAGE DRAWING	PINS	PACKAGE QTY
OPT101P	ACTIVE	PDIP	NTC	8	50
OPT101P-J	ACTIVE	SOP	DTL	8	50

(1) The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

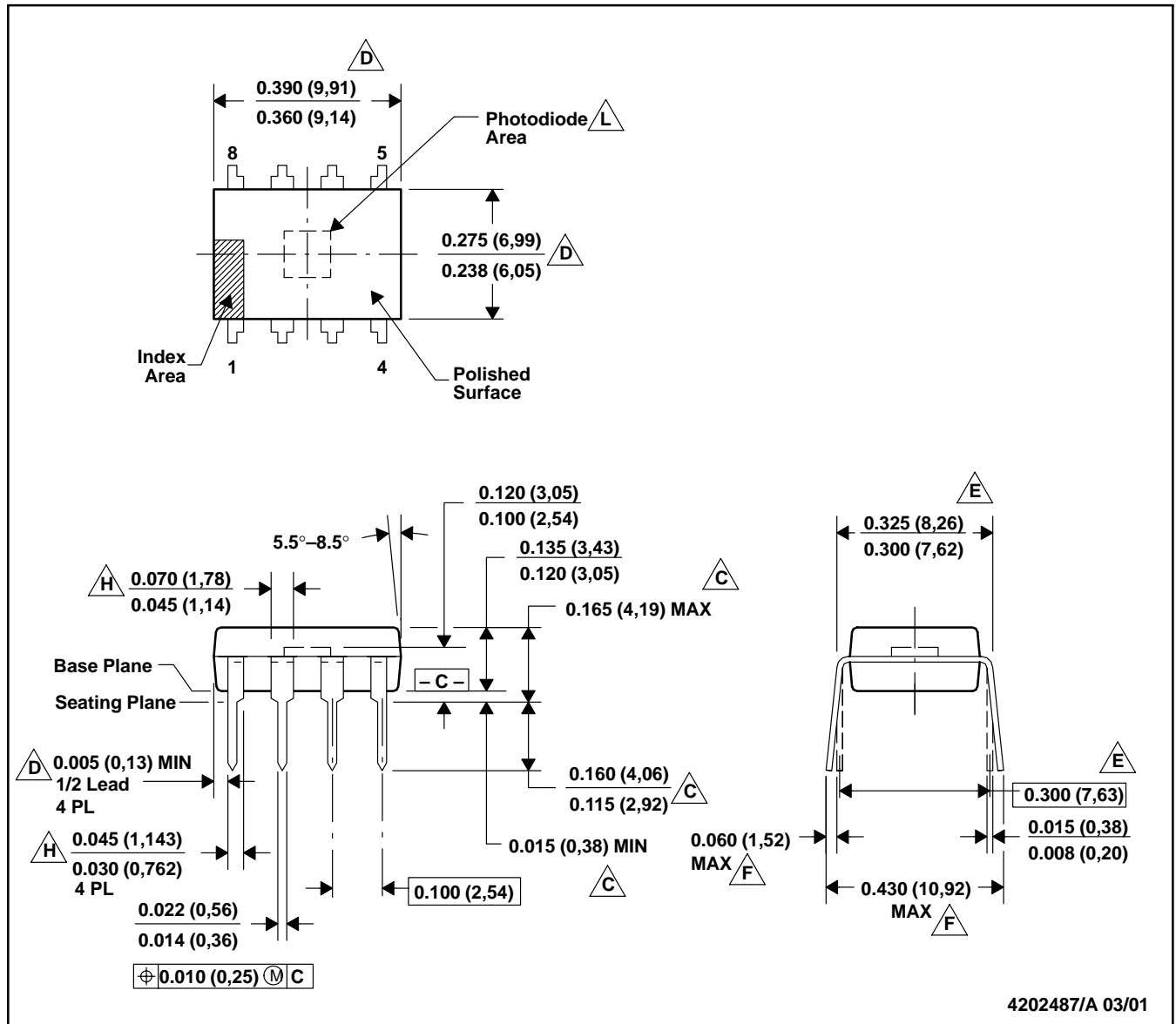
**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

## NTC (R-PDIP-T8)

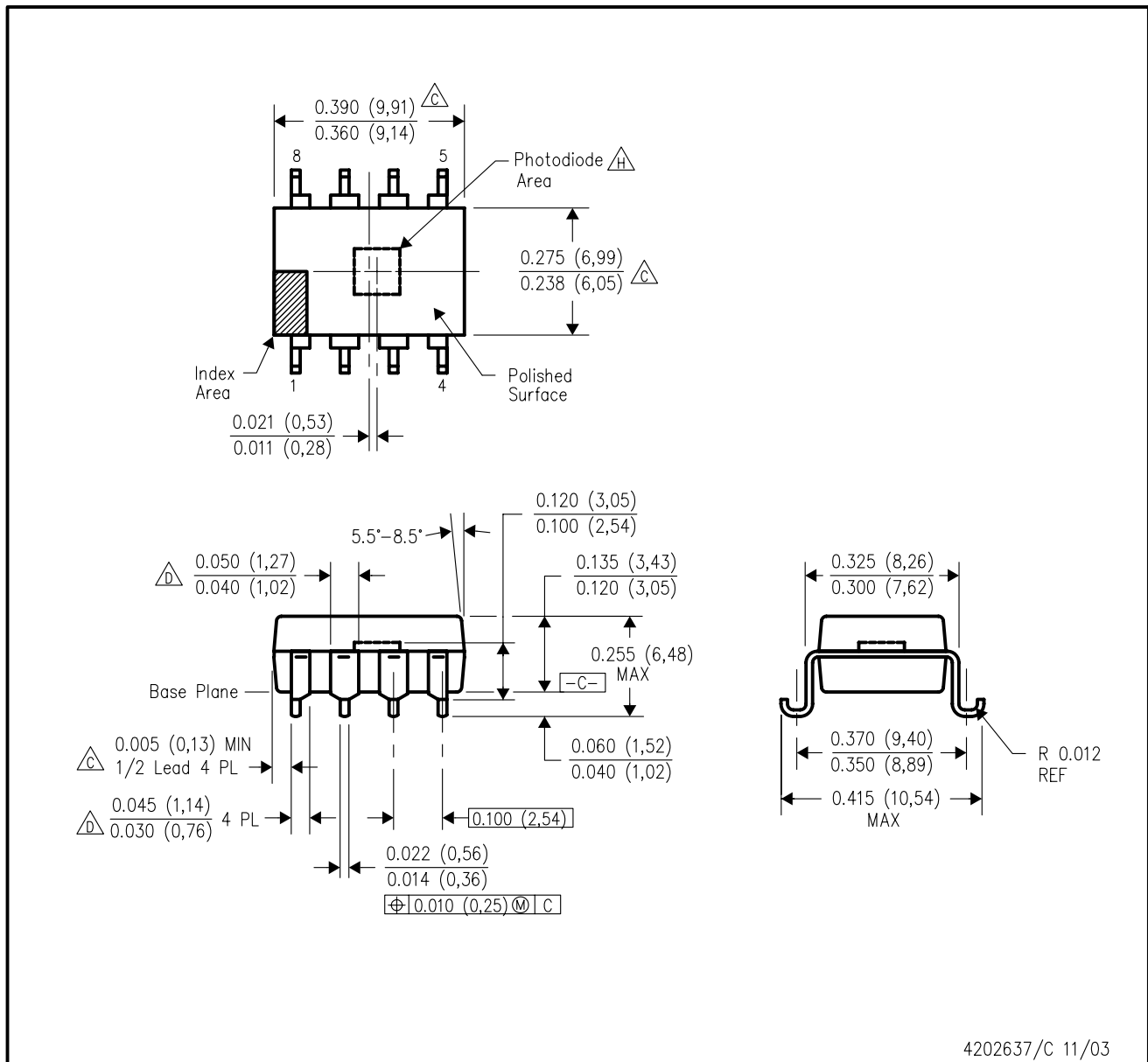
## PLASTIC DUAL-IN-LINE



- NOTES:
- A. All linear dimensions are in inches (millimeters).
  - B. This drawing is subject to change without notice.
  - C. Dimensions are measured with the package seated in JEDEC seating plane gauge GS-3.
  - D. Dimensions do not include mold flash or protrusions. Mold flash or protrusions shall not exceed 0.010 (0,25).
  - E. Dimensions measured with the leads constrained to be perpendicular to Datum C.
  - F. Dimensions are measured at the lead tips with the leads unconstrained.
  - G. Pointed or rounded lead tips are preferred to ease insertion.
  - H. Maximum dimensions do not include dambar protrusions. Dambar protrusions shall not exceed 0.010 (0,25).
  - I. Distance between leads including dambar protrusions to be 0.005 (0,13) minimum.
  - J. A visual index feature must be located within the cross-hatched area.
  - K. For automatic insertion, any raised irregularity on the top surface (step, mesa, etc.) shall be symmetrical about the lateral and longitudinal package centerlines.
  - L. Center of photodiode must be within 0.010 (0,25) of center of photodiode area

DTL (R-PDSO-U8)

PLASTIC SMALL-OUTLINE



4202637/C 11/03

- NOTES:
- A. All linear dimensions are in inches (millimeters).
  - B. This drawing is subject to change without notice.
  - $\Delta$  C Dimensions do not include mold flash or protrusions. Mold flash or protrusions shall not exceed 0.010 (0,25).
  - $\Delta$  D Maximum dimensions do not include dambar protrusions. Dambar protrusions shall not exceed 0.010 (0,25).
  - E. Distance between leads including dambar protrusions to be 0.005 (0,13) minimum.
  - F. A visual index feature must be located within the cross-hatched area.
  - G. For automatic insertion, any raised irregularity on the top surface (step, mesa, etc.) shall be symmetrical about the lateral and longitudinal package centerlines.
  - $\Delta$  H Center of photodiode must be within 0.010 (0,25) of center of photodiode area.

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